

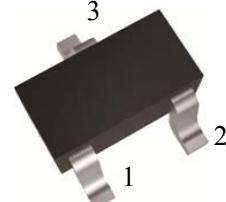
N-Channel Enhancement Mode MOSFET
Feature

- 30V/5.8A, RDS(ON) = 35mΩ(MAX) @VGS = 10V.
- RDS(ON) = 40mΩ(MAX) @VGS = 4.5V.
- RDS(ON) = 55mΩ(MAX) @VGS = 2.5V.

- Super High dense cell design for extremely low RDS(ON).
- Reliable and Rugged.
- SC-59 for Surface Mount Package.

Applications

- Power Management
- Portable Equipment and Battery Powered Systems.
- Marking:AOLA LT

SC-59


1 : Gate 2 : Source 3 : Drain

Absolute Maximum Ratings

TA=25°C Unless Otherwise noted

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±12	V
Drain Current-Continuous	I _D	5.8	A

Electrical Characteristics

TA=25°C Unless Otherwise noted

Parameter	Symbol	Test Conditions	Min	Typ.	Max	Units
Off Characteristics						
Drain to Source Breakdown Voltage	BVDSS	VGS=0V, ID=250μA	30	-	-	V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V	-	-	1	μA
Gate Body Leakage Current, Forward	IGSSF	VGS=12V, VDS=0V	-	-	100	nA
Gate Body Leakage Current, Reverse	IGSSR	VGS=-12V, VDS=0V	-	-	-100	nA
On Characteristics						
Gate Threshold Voltage	VGS(th)	VGS=VDS, ID=250μA	0.6	-	1.5	V
Static Drain-source On-Resistance	RDS(ON)	VGS =10V, ID =5.8A	-	30	35	mΩ
		VGS =4.5V, ID =5A	-	33	40	mΩ
		VGS =2.5V, ID =4A	-	45	55	mΩ
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Voltage	VSD	VGS =0V, IS=1.25A			1.2	V

Dynamic

Q _g	Total Gate Charge	VDS=15V,VGS=10V,Id=2A	8.5	12	nC
Q _{gs}	Gate-Source Charge		1.1		
Q _{gd}	Gate-Drain Charge		1.8		
t _{on}	Turn-on Time	VDD=15V,Id=2A,VGS=10V,RG=6Ω		40	nS
t _{d(ON)}	Turn-on Delay time			11	
t _r	Turn-on Rise Time			17	
T _{d(off)}	Turn-off Delay Time			37	
t _f	Turn-off Fall Time			20	
t _{off}	Turn-off Time			60	

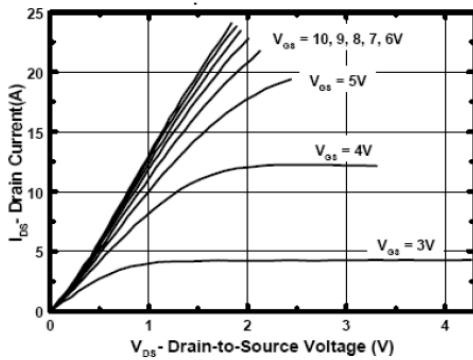


Figure 1. Output Characteristics

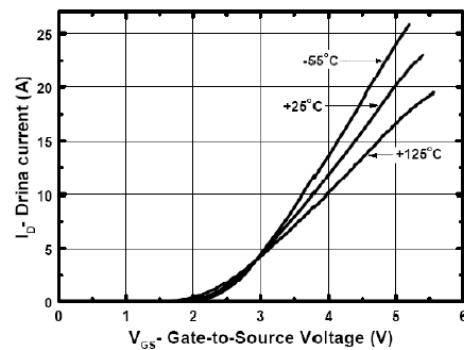


Figure 2. Transfer Characteristics

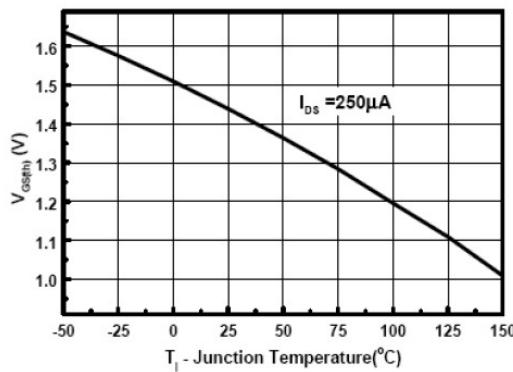


Figure 3. Gate Threshold Variation with Temperature

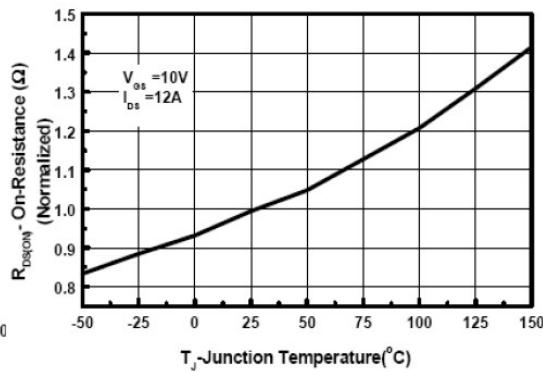


Figure 4. On-Resistance Variation with Temperature

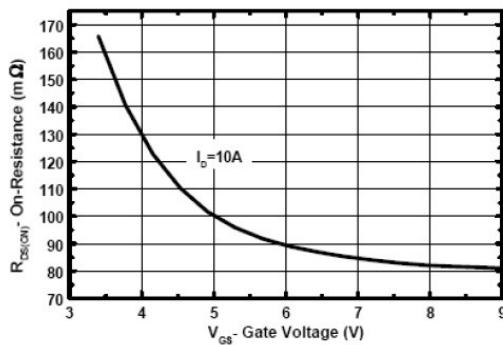


Figure 5. On-Resistance vs. Gate-to-Source Voltage

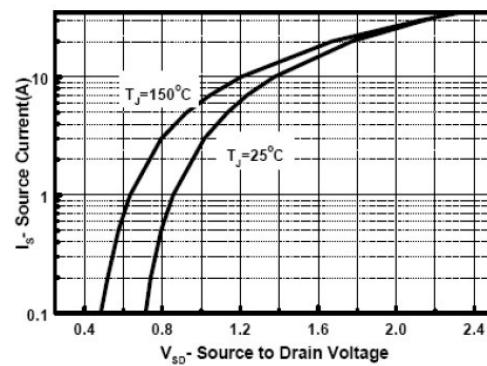


Figure 6. Source-Drain Diode Forward Voltage

Package Outline Dimensions (UNIT: mm)

SC-59

